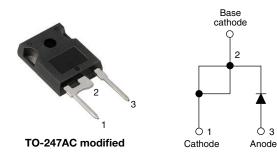


Vishay Semiconductors

High Voltage, Input Rectifier Diode, 40 A



PRODUCT SUMMARY					
Package	TO-247AC modified (2 pins)				
I _{F(AV)}	40 A				
V _R	800 V to 1200 V				
V _F at I _F	1.1 V				
I _{FSM}	475 A				
T _J max.	150 °C				
Diode variation	Single die				

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction
- \bullet Designed and qualified according to JEDEC $^{\textcircled{B}}\mbox{-}\mbox{JESD}$ 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Sinusoidal waveform	40	А				
V _{RRM}	Range	800/1200	V				
I _{FSM}		475	А				
V _F	40 A, T _J = 25 °C	1.1	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS						
PART NUMBER	I _{RRM} AT 150 ℃ mA					
VS-40EPS08PbF, VS-40EPS08-M3	800	900	1			
VS-40EPS12PbF, VS-40EPS12-M3	1200	1300	1			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	$T_C = 105 \ ^{\circ}C$, 180° conduction half sine wave	40			
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V_{RRM} applied	400	А		
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	475			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	800	A ² s		
Maximum -t for fusing	1-1	10 ms sine pulse, no voltage reapplied	1131	A-5		
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	11 310	A²√s		

Revision: 12-Oct-16 For technical questions within

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum forward voltage drop	M	20 A, T _J = 25 °C		1.0	V	
	V _{FM}	40 A, T _J = 25 °C		1.1	v	
Forward slope resistance	r _t	T ₁ = 150 °C		7.16	mΩ	
Threshold voltage	V _{F(TO)}	1j = 150 C		0.74	V	
Maximum reverse leakage aurrent	1	$T_J = 25 ^{\circ}C$	0.1	mA		
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	$V_R = Rated V_{RRM}$	1.0	ША	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storrage temperature range)	T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.6		
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, flat, smooth and greased	0.2		
Approvimate weight				6	g	
Approximate weight				0.21	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
Mounting torque	maximum			12 (10)	(lbf ⋅ in)	
Madaaaaa			Coop atula TO 247AC modified (JEDEC)	40EPS08		
Marking device			Case style TO-247AC modified (JEDEC)		40EPS12	

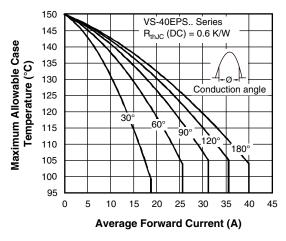


Fig. 1 - Current Rating Characteristics

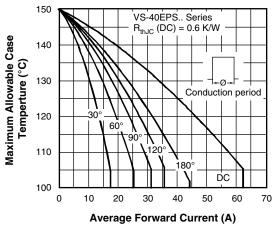


Fig. 2 - Current Rating Characteristics



VS-40EPS..PbF Series, VS-40EPS..-M3 Series

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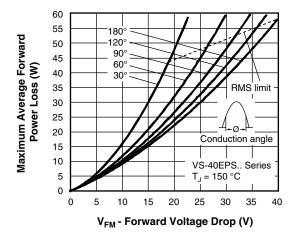


Fig. 3 - Forward Power Loss Characteristics

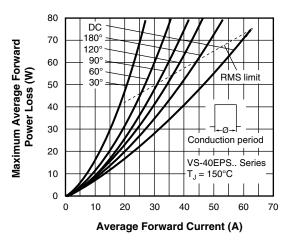


Fig. 4 - Forward Power Loss Characteristics

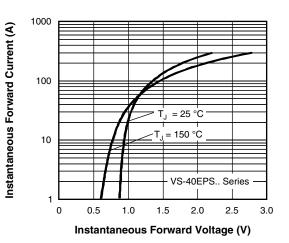
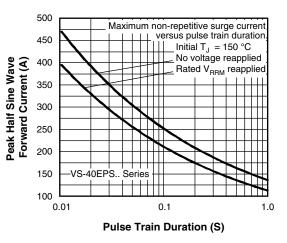


Fig. 5 - Forward Voltage Drop Chacteristics





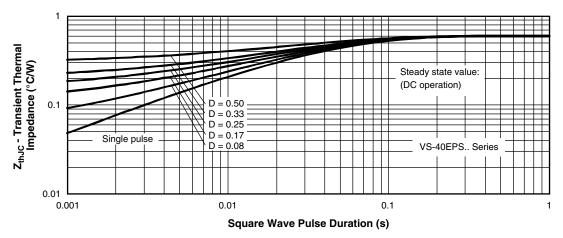
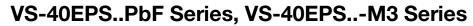


Fig. 7 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code	VS-	40	Е	Р	s	12	PbF
		(2)	(3)	(4)	(5)	(6)	$\overline{(7)}$
	\cup		\bigcirc	9	\bigcirc	\bigcirc	\cup
	1.	- Visł	nay Sem	niconduc	ctors pro	duct	
	2 - Current rating (40 = 40 A)						
	3 -	- Circ	uit confi	iguratior	1:		
		E = single diode					
	4 -		kage:				
	<u> </u>		TO-247	AC mor	lified		
	5.	-	e of silic		incu		
			standar		erv recti	fier 🗌	
					cry root		08 = 80
	6 -		age rati	0			12 = 120
	7	- Env	ironmer	ital digit:			
		PbF	= lead	(Pb)-fre	e and R	oHS-co	mpliant
		-M3	- haloo	on_froo	PoHS-	complia	ont and

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-40EPS08PbF	25	500	Antistatic plastic tubes				
VS-40EPS08-M3	25	500	Antistatic plastic tubes				
VS-40EPS12PbF	25	500	Antistatic plastic tubes				
VS-40EPS12-M3	25	500	Antistatic plastic tubes				

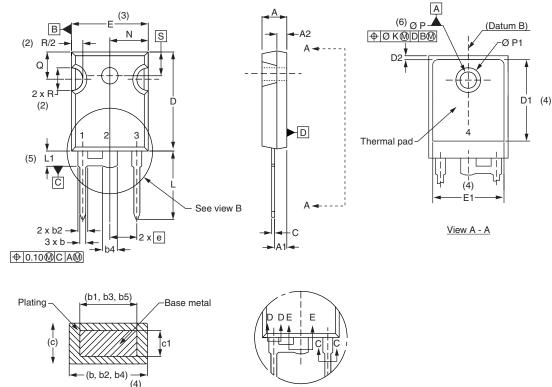
LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95541			
Deut mend in er informetien	TO-247AC modified PbF	www.vishay.com/doc?95255			
Part marking information	TO-247AC modified -M3	www.vishay.com/doc?95442			
SPICE model		www.vishay.com/doc?96047			





TO-247 - 50 mils L/F modified

DIMENSIONS in millimeters and inches



Section C - C, D - D, E - E



View	В

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	MILLIMETERS INCHES		NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØК	0.2	0.254)10	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62	BSC	0.3		
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	BSC	

Notes

- ⁽¹⁾ Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q

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